# Logic controlled high-side power switch

Rev. 1 — 7 July 2015

**Product data sheet** 

## 1. General description

The NX5P2925C is a high-side load switch which features a low ON resistance N-channel MOSFET with controlled slew rate that supports 2.5 A of continuous current. Designed for operation from 0.8 V to 5.5 V, it is used in power domain isolation applications to reduce power dissipation and extend battery life. The enable logic includes integrated logic level translation making the device compatible with lower voltage processors and controllers. The NX5P2925C is ideal for portable, battery operated applications due to low ground current.

NX5P2925C features reverse current protection (RCP) circuits. If VOUT exceeds VIN by 25 mV, the RCP circuit isolates VOUT from VIN, preventing damage to devices on the input side of the switch.

## 2. Features and benefits

- Wide supply voltage range from 0.8 V to 5.5 V
- Very low ON resistance:
  - 18 m $\Omega$  (typical) at a supply voltage of 1.2 V
  - 18 mΩ (typical) at a supply voltage of 1.8 V
- High noise immunity
- High current handling capability (2.5 A continuous current)
- Reverse current protection
- Turn-on slew rate limiting
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
- Specified from –40 °C to +85 °C

# 3. Applications

- Cell phone
- Digital cameras and audio devices
- Portable and battery-powered equipment



Logic controlled high-side power switch

# 4. Ordering information

Gable 1.         Ordering information							
Type number Package							
	Temperature range	Name	Description	Version			
NX5P2925CUK	–40 °C to +85 °C	WLCSP6	wafer level chip-scale package; 6 bumps; 0.87 $\times$ 1.37 $\times$ 0.5 mm	NX5P2925C			

# 5. Marking

Table 2.   Marking codes	
Type number	Marking code
NX5P2925CUK	5C

# 6. Functional diagram





2 of 20

Logic controlled high-side power switch

# 7. Pinning information

## 7.1 Pinning



## 7.2 Pin description

Table 3. Pin description							
Symbol	Pin	Description					
VIN	A2, B2	input voltage					
GND	C1	ground (0 V)					
EN	C2	enable input (active HIGH)					
VOUT	A1, B1	output voltage					

# 8. Functional description

### Table 4.Function table<sup>[1]</sup>

Input EN	Switch			
L	switch OFF			
Н	switch ON			

[1] H = HIGH voltage level; L = LOW voltage level.

Logic controlled high-side power switch

# 9. Application diagram

The NX5P2925C is typically used in portable, battery operated device. Pin EN enables the NX5P2925C. Slew rate controlled in-rush current reduction circuits function during switching.



### Logic controlled high-side power switch

# **10. Limiting values**

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
VI	input voltage	input EN	[1]	-0.5	V <sub>I(VIN)</sub>	V
		input VIN	[2]	-0.5	+6.0	V
V <sub>SW</sub>	switch voltage	output VOUT	[2]	-0.5	V <sub>I(VIN)</sub>	V
I <sub>IK</sub>	input clamping current	input EN: V <sub>I(EN)</sub> < -0.5 V		-50	-	mA
I <sub>SK</sub>	switch clamping current	input VIN: $V_{I(VIN)} < -0.5 V$		-50	-	mA
		output VOUT: $V_{O(VOUT)} < -0.5 V$		-50	-	mA
		output VOUT: $V_{O(VOUT)} > V_{I(VIN)} + 0.5 V$		-	50	mA
I <sub>SW</sub>	switch current	V <sub>SW</sub> > -0.5 V		-	±2500	mA
		pulsed, 100 ms pulse, 2 % duty cycle		-	±5000	mA
T <sub>j(max)</sub>	maximum junction temperature			-40	+125	°C
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation		[3]	-	470	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] The (absolute) maximum power dissipation depends on the junction temperature  $T_j$ . Higher power dissipation is allowed in conjunction with lower ambient temperatures. The conditions to determine the specified values are  $T_{amb} = 85$  °C and the use of a two layer PCB.

# 11. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
VI	input voltage	input EN	0	V <sub>I(VIN)</sub>	V
		input VIN	0.8	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+85	°C

### Logic controlled high-side power switch

# 12. Thermal characteristics

Table 7. Ther				
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	[1]	139	K/W

 $R_{th(j-a)}$  is dependent upon board layout. To minimize  $R_{th(j-a)}$ , ensure that all pins have a solid connection to larger copper layer areas. In multi-layer PCBs, the second layer should be used to create a large heat spreader area below the device. Avoid using solder-stop [1] varnish under the device.

## 13. Static characteristics

#### Table 8. **Static characteristics**

 $V_{I(V|N)} = 1.0 \text{ V to } 5.5 \text{ V}$ , unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> = -40 °	C to +85 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input	EN input; $V_{I(VIN)} = 0.8 V$	0.6	-	-	0.6	-	V
	voltage	EN input; $V_{I(VIN)} = 1.0$ V to 1.2 V	0.9	-	-	0.9	-	V
		EN input; $V_{I(VIN)} = 1.2$ V to 2.5 V	1.2	-	-	1.2	-	V
		EN input; $V_{I(VIN)} = 2.5 \text{ V}$ to 5.5 V	1.2	-	-	1.2	-	V
V <sub>IL</sub>	LOW-level input	EN input; $V_{I(VIN)} = 0.8 V$	-	-	0.25	-	0.25	V
	voltage	EN input; $V_{I(VIN)} = 1.0$ V to 1.2 V	-	-	0.3	-	0.3	V
		EN input; $V_{I(VIN)} = 1.2$ V to 2.5 V	-	-	0.4	-	0.4	
		EN input; $V_{I(VIN)} = 2.5 \text{ V}$ to 5.5 V	-	-	0.6	-	0.6	
l <sub>l</sub>	input leakage current	EN input; $V_{I(EN)} = 0.9 V$ to 5.5 V	-	-	-	-	0.1	μA
V <sub>trig</sub>	trigger voltage	RCP; $V_{trig} = V_{(VOUT)} - V_{(VIN)}$	-	25	-	-	40	mV
V <sub>H</sub>	hysteresis voltage	V <sub>trig</sub>	-	3	-	-	15	mV
I <sub>DD</sub>	supply current	VOUT open						
		EN = HIGH; V <sub>I(VIN)</sub> = 1.0 V; see <u>Figure 6</u> and <u>Figure 7</u>	-	45	-	-	65	μA
		EN = HIGH; V <sub>I(VIN)</sub> = 1.8 V; see <u>Figure 6</u> and <u>Figure 7</u>	-	50	-	-	70	μA
		EN = HIGH; V <sub>I(VIN)</sub> = 3.6 V; see <u>Figure 6</u> and <u>Figure 7</u>	-	65	-	-	95	μA
		EN = HIGH; V <sub>I(VIN)</sub> = 5.5 V; see <u>Figure 6</u> and <u>Figure 7</u>	-	115	-	-	150	μA
		EN = LOW;	-	0.1	-	-	1.5	μA
		see Figure 8 and Figure 9						

### Logic controlled high-side power switch

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C	C to +85 °C	Unit
			Min	Typ[1]	Max	Min	Max	
I <sub>S(OFF)</sub>	OFF-state leakage current	$\label{eq:loss} \begin{array}{l} \text{EN} = \text{LOW}; \ \text{V}_{\text{I}(\text{VIN})} = 1.8 \ \text{V}; \\ \text{V}_{\text{I}(\text{VOUT})} = 0 \ \text{V}; \ \text{see} \ \underline{\text{Figure 10}} \ \text{and} \\ \hline \end{array} \begin{array}{l} \text{Figure 11} \end{array}$	-	-0.5	-	-3.5	-	μA
		$\label{eq:VIVIN} \begin{split} &EN = LOW; \ V_{I(VIN)} = 3.6 \ V; \\ &V_{I(VOUT)} = 0 \ V; \ see \ \underline{Figure 10} \ and \\ & \overline{Figure 11} \end{split}$	-	-0.5	-	-5.0	-	μA
		$\label{eq:expansion} \begin{split} &EN = LOW;  V_{I(VIN)} = 5.5 \; V; \\ &V_{I(VOUT)} = 0 \; V;  see \; \underline{Figure 10} \; and \\ & \overline{Figure 11} \end{split}$	-	-0.5	-	-7.5	-	μA
CI	input capacitance	EN	-	3	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	VIN; VOUT	-	-	0.5	-	0.5	nF

#### Table 8. Static characteristics ...continued

 $V_{I(VIN)} = 1.0 \text{ V to 5.5 V}$ , unless otherwise specified; Voltages are referenced to GND (ground = 0 V). ...continued

[1] All typical values are measured at  $V_{I(VIN)}$  = 3.6 V and  $T_{amb}$  = 25 °C unless otherwise specified.



## 13.1 Graphs

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# NX5P2925C

### Logic controlled high-side power switch



Fig 10. Typical OFF-state leakage current versus temperature



NX5P2925C **Product data sheet** 

Logic controlled high-side power switch

## 13.2 ON resistance

#### Table 9. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Ta	T <sub>amb</sub> = 25 °C		$T_{amb} = -40$	Unit	
			Min	Тур	Max	Min	Max	
R <sub>ON</sub>	ON resistance	$V_{I(EN)} = V_{I(VIN)}$ ; $I_{LOAD} = 200 \text{ mA}$ ; see <u>Figure 12</u> , <u>13</u> and <u>14</u>						
		V <sub>I(VIN)</sub> = 0.8 V	-	21	-	-	26	mΩ
		$V_{I(VIN)} = 0.9 V$	-	19	-	-	24	mΩ
		$V_{I(VIN)} = 1.0 V \text{ to } 5.5 V$	-	18	-	-	23	mΩ

## 13.3 ON resistance test circuit and graphs







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### Logic controlled high-side power switch

# **14. Dynamic characteristics**

### Table 10. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 16.

Symbol	Parameter	Conditions	Ta	amb = 25	°C	T <sub>amb</sub> = -40 °	C to +85 °C	Unit
			Min	Тур	Max	Min	Max	_
t <sub>en</sub>	enable time	EN to VOUT; see <u>Figure 15</u> , <u>17, 18</u> and <u>19</u>						
		V <sub>I(VIN)</sub> = 0.8 V	-	630	-	-	-	μs
		V <sub>I(VIN)</sub> = 1.0 V	-	530	-	250	-	μs
		V <sub>I(VIN)</sub> = 3.6 V	-	510	-	300	-	μs
		V <sub>I(VIN)</sub> = 5.5 V	-	510	-	350	-	μs
t <sub>dis</sub>	disable time	EN to VOUT; see Figure 15 and 20						
		V <sub>I(VIN)</sub> = 0.8 V	-	74	-	-	-	μS
		$V_{I(VIN)} = 1.0 V$	-	20	-	-	-	μS
		V <sub>I(VIN)</sub> = 3.6 V	-	4	-	-	-	μs
		V <sub>I(VIN)</sub> = 5.5 V	-	2.5	-	-	-	μs
t <sub>on</sub>	turn-on time	EN to VOUT; see <u>Figure 15</u> , <u>17, 18</u> and <u>19</u>						
		V <sub>I(VIN)</sub> = 0.8 V	-	990	-	-	-	μs
		V <sub>I(VIN)</sub> = 1.0 V	-	940	-	500	-	μs
		V <sub>I(VIN)</sub> = 3.6 V	-	1290	-	800	-	μs
		V <sub>I(VIN)</sub> = 5.5 V	-	1480	-	1000	-	μs
t <sub>off</sub>	turn-off time	EN to VOUT; see Figure 15 and 20						μS
		V <sub>I(VIN)</sub> = 0.8 V	-	89	-	-	-	μs
		V <sub>I(VIN)</sub> = 1.0 V	-	25	-	-	-	μs
		V <sub>I(VIN)</sub> = 3.6 V	-	8	-	-	-	μs
		V <sub>I(VIN)</sub> = 5.5 V	-	6	-	-	-	μs
t <sub>TLH</sub>	LOW to HIGH	VOUT; see Figure 15						
	output transition time	V <sub>I(VIN)</sub> = 0.8 V	-	360	-	-	-	μs
		V <sub>I(VIN)</sub> = 1.0 V	-	410	-	150	-	μs
		V <sub>I(VIN)</sub> = 3.6 V	-	780	-	400	-	μs
		V <sub>I(VIN)</sub> = 5.5 V	-	970	-	560	-	μs
t <sub>THL</sub>	HIGH to LOW	VOUT; see Figure 15						
	output transition time	V <sub>I(VIN)</sub> = 0.8 V	-	15	-	-	-	μS
		V <sub>I(VIN)</sub> = 1.0 V	-	4.5	-	-	-	μS
		V <sub>I(VIN)</sub> = 3.6 V	-	4.3	-	-	-	μS
		V <sub>I(VIN)</sub> = 5.5 V	-	3.7	-	-	-	μs

### Logic controlled high-side power switch

## 14.1 Waveforms, graphs and test circuit



#### Table 11. Measurement points

Supply voltage	EN Input	Output			
V <sub>I(VIN)</sub>	V <sub>M</sub>	V <sub>X</sub> V <sub>Y</sub>			
1.0 V to 5.5 V	$0.5  imes V_{I(EN)}$	$0.1 \times V_{OH}$	$0.9  imes V_{OH}$		



#### Table 12. Test data

Supply voltage	Input	Load	
V <sub>EXT</sub>	V <sub>I(EN)</sub>	CL	RL
1.0 V to 5.5 V	V <sub>I(VIN)</sub>	0.1 μF	10 Ω

NX5P2925C

11 of 20

## **NXP Semiconductors**

# NX5P2925C

### Logic controlled high-side power switch



### Logic controlled high-side power switch



NX5P2925C

13 of 20

Logic controlled high-side power switch

# 15. Package outline



Fig 23. Package outline NX5P2925C

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#### Logic controlled high-side power switch

## **16. Soldering of WLCSP packages**

### 16.1 Introduction to soldering WLCSP packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering WLCSP (Wafer Level Chip-Size Packages) can be found in application note *AN10439 "Wafer Level Chip Scale Package"* and in application note *AN10365 "Surface mount reflow soldering description"*.

Wave soldering is not suitable for this package.

All NXP WLCSP packages are lead-free.

### 16.2 Board mounting

Board mounting of a WLCSP requires several steps:

- 1. Solder paste printing on the PCB
- 2. Component placement with a pick and place machine
- 3. The reflow soldering itself

### 16.3 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 24</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues, such as smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature), and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic) while being low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with <u>Table 13</u>.

Package thickness (mm)	Package reflow temperature (°C) Volume (mm <sup>3</sup> )			
	< 1.6	260	260	260
1.6 to 2.5	260	250	245	
> 2.5	250	245	245	

#### Table 13. Lead-free process (from J-STD-020D)

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 24.

Logic controlled high-side power switch



For further information on temperature profiles, refer to application note AN10365 "Surface mount reflow soldering description".

### 16.3.1 Stand off

The stand off between the substrate and the chip is determined by:

- The amount of printed solder on the substrate
- The size of the solder land on the substrate
- The bump height on the chip

The higher the stand off, the better the stresses are released due to TEC (Thermal Expansion Coefficient) differences between substrate and chip.

### 16.3.2 Quality of solder joint

A flip-chip joint is considered to be a good joint when the entire solder land has been wetted by the solder from the bump. The surface of the joint should be smooth and the shape symmetrical. The soldered joints on a chip should be uniform. Voids in the bumps after reflow can occur during the reflow process in bumps with high ratio of bump diameter to bump height, i.e. low bumps with large diameter. No failures have been found to be related to these voids. Solder joint inspection after reflow can be done with X-ray to monitor defects such as bridging, open circuits and voids.

### 16.3.3 Rework

In general, rework is not recommended. By rework we mean the process of removing the chip from the substrate and replacing it with a new chip. If a chip is removed from the substrate, most solder balls of the chip will be damaged. In that case it is recommended not to re-use the chip again.

### Logic controlled high-side power switch

Device removal can be done when the substrate is heated until it is certain that all solder joints are molten. The chip can then be carefully removed from the substrate without damaging the tracks and solder lands on the substrate. Removing the device must be done using plastic tweezers, because metal tweezers can damage the silicon. The surface of the substrate should be carefully cleaned and all solder and flux residues and/or underfill removed. When a new chip is placed on the substrate, use the flux process instead of solder on the solder lands. Apply flux on the bumps at the chip side as well as on the solder pads on the substrate. Place and align the new chip while viewing with a microscope. To reflow the solder, use the solder profile shown in application note *AN10365 "Surface mount reflow soldering description"*.

### 16.3.4 Cleaning

Cleaning can be done after reflow soldering.

## **17. Abbreviations**

### Table 14.Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
IEC	International Electrotechnical Commission
MOSFET	Metal-Oxide Semiconductor Field Effect Transistor

# 18. Revision history

### Table 15.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX5P2925C v.1	20150707	Product data sheet	-	-

#### Logic controlled high-side power switch

# **19. Legal information**

### **19.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## Logic controlled high-side power switch

# 21. Contents

1	General description	. 1
2	Features and benefits	. 1
3	Applications	. 1
4	Ordering information	. 2
5	Marking	. 2
6	Functional diagram	. 2
7	Pinning information	. 3
7.1	Pinning	. 3
7.2	Pin description	. 3
8	Functional description	. 3
9	Application diagram	. 4
10	Limiting values	. 5
11	Recommended operating conditions	. 5
12	Thermal characteristics	. 6
13	Static characteristics	. 6
13.1	Graphs	. 7
13.2	ON resistance	
13.3	ON resistance test circuit and graphs	
14	Dynamic characteristics	10
14.1	Waveforms, graphs and test circuit	11
15	Package outline	14
16	Soldering of WLCSP packages	15
16.1	Introduction to soldering WLCSP packages	15
16.2	Board mounting	15
16.3	Reflow soldering	15
16.3.1	Stand off	16
16.3.2 16.3.3	Quality of solder joint	16 16
16.3.4	Rework	10
10.0.4 17	Abbreviations	17
18	Revision history	17
19	Legal information.	18
19.1	Data sheet status	18
19.1		18
19.2	Disclaimers	18
19.4	Trademarks.	19
20	Contact information	19
21	Contents	-

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Date of release: 7 July 2015 Document identifier: NX5P2925C

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